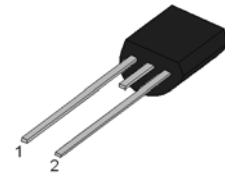


DESCRIPTION:

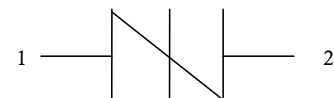
PxxxxEC series thyristors are a type of semiconductor component. They are designed in applications: modems, telephones, line cards, answering machines, FAX machines, SLICs, T1/E1, xDSL, PBXs and more.



TO-92

FEATURES:

- Excellent capability of absorbing transient surge.
- Quick response to surge voltage (ns Level).
- Eliminates overvoltage caused by fast rising transients.
- Moisture sensitivity level: Level 1.
- Non degenerative.
- Package way: 1000pcs / bag.



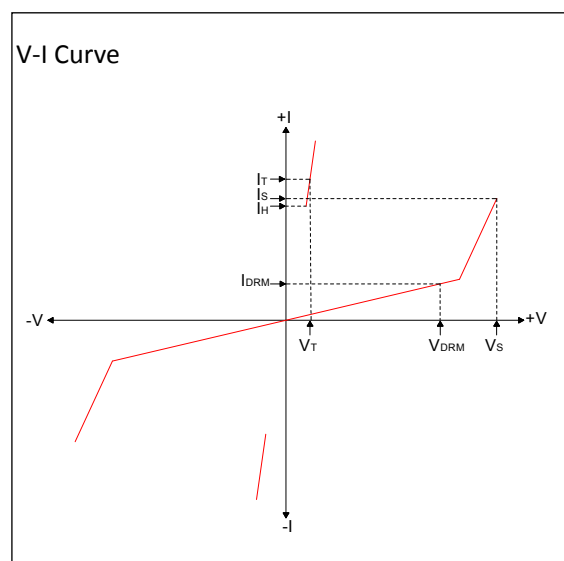
Symbol

ABSOLUTE MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$, unless otherwise noted)

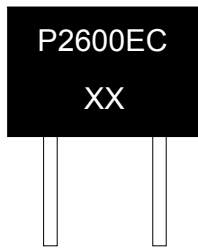
Parameter	Symbol	Value	Unit
Storage temperature range	T_{STG}	-60 to +150	$^{\circ}\text{C}$
Operating junction temperature range	T_J	-40 to +125	$^{\circ}\text{C}$
Repetitive peak pulse current	I_{PP}	100	A

ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$)

Symbol	Parameter
V_{DRM}	Peak off-state voltage
I_{DRM}	Off-state current
V_S	Switching voltage
I_S	Switching current
V_T	On-state voltage
I_T	On-state current
I_H	Holding current
C_O	Off-state capacitance



MARKING



P2600EC: Device Marking Code
XX: The production cycle

ELECTRICAL CHARACTERISTICS (T_A=25°C, continued)

Part Number	I _{DRM} @V _{DRM}		V _S @I _S		V _T @ I _T		I _H	C _O ^①	Marking
	μA	V	V	mA	V	A	mA	pF	
	max		max		max	max	min	max	
P0080EC	1	6	15	800	4	2.2	50	80	P0080EC
P0640EC	1	58	77	800	4	2.2	120	200	P0640EC
P0720EC	1	65	87	800	4	2.2	120	150	P0720EC
P2300EC	1	190	260	800	4	2.2	150	60	P2300EC
P2600EC	1	220	300	800	4	2.2	150	60	P2600EC
P3100EC	1	275	350	800	4	2.2	150	50	P3100EC
P3500EC	1	320	400	800	4	2.2	150	50	P3500EC

① V_S is measured at 100KV/s

② Off-state capacitance is measured in V_{DC}=2V, V_{RMS}=1V, f=1MHz

SURGE RATINGS (Temperature range: -40 ~+85°C)

Series	I _{PP} (A) min			
	2×10μs	8×20μs	10×360μs	10×1000μs
C	500	400	175	100

ORDERING INFORMATION

P	008	0	E	C
Series code P: SIDACtor	Median voltage	0: Bi-direction 1: Uni-direction	Package type: TO-92-2L	Surge ratings: 6KV(10/700μs)



SOLDERING PARAMETERS

Reflow Condition		Pb-Free assembly (see FIG.2)
Pre Heat	-Temperature Min ($T_{s(min)}$)	+150°C
	-Temperature Max($T_{s(max)}$)	+200°C
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquidus Temp (T_L) to peak)		3°C/sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature(T_L) (Liquidus)	+217°C
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_p)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (t_p)		30 secs. Max
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp (T_P)		8 min. Max
Do not exceed		+260°C

FIG.1: tr × td pulse waveform

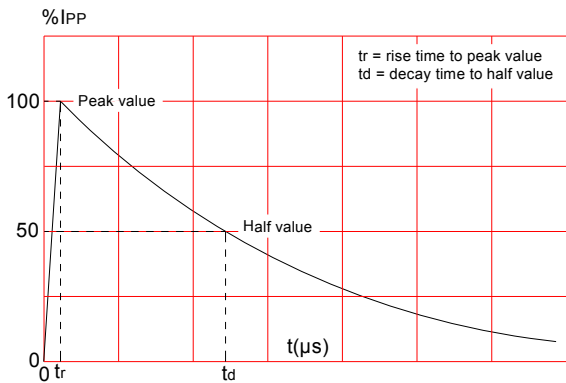


FIG.3: Normalized V_s change vs. junction temperature

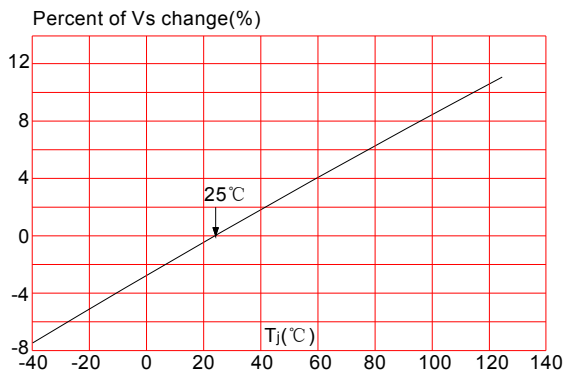


FIG.2: Reflow condition

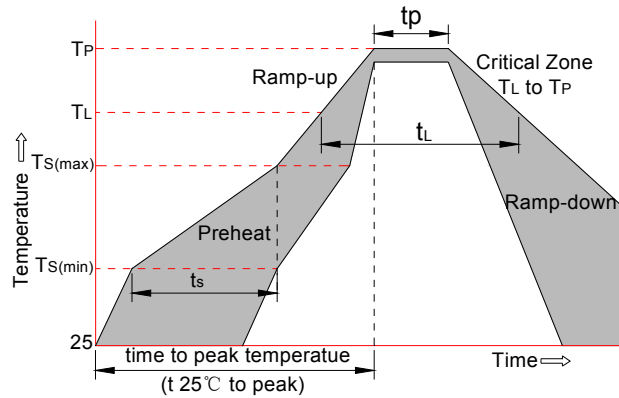
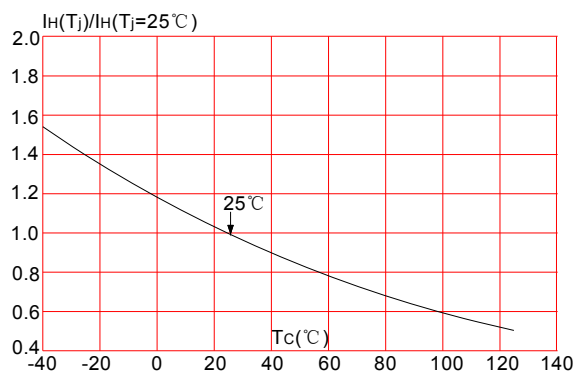
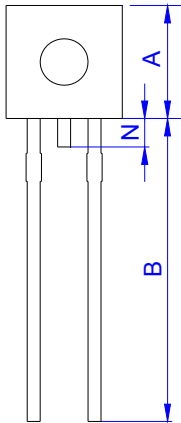
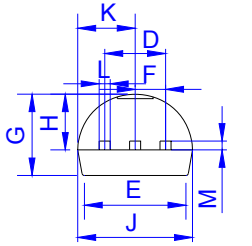


FIG.4: Normalized DC holding current vs. case temperature





PACKAGE MECHANICAL DATA



TO-92

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.32	5.33	0.170	0.210
B	12.70	15.00	0.500	0.591
D	2.41	2.67	0.095	0.105
E	-	4.3	-	0.169
F	1.16	1.37	0.046	0.054
G	3.18	4.19	0.125	0.165
H	2.04	2.66	0.080	0.105
J	4.45	5.20	0.175	0.205
K	2.04	2.66	0.080	0.105
L	0.41	0.53	0.016	0.021
M	0.36	0.50	0.014	0.020
N	-	1.52	-	0.060